

2SD1418

Silicon NPN Epitaxial

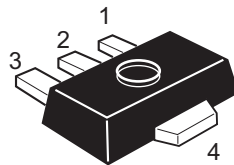
REJ03G0787-0200
 (Previous ADE-208-1149)
 Rev.2.00
 Aug.10.2005

Application

- Low frequency power amplifier
- Complementary pair with 2SB1025

Outline

RENESAS Package code: PLZZ0004CA-A
 (Package name: UPAK[®])



1. Base
2. Collector
3. Emitter
4. Collector (Flange)

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Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	120	V
Collector to emitter voltage	V_{CEO}	80	V
Emitter to base voltage	V_{EBO}	5	V
Collector current	I_C	1	A
Collector peak current	$i_{C(peak)}^{*1}$	2	A
Collector power dissipation	P_C^{*2}	1	W
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

Notes: 1. $PW \leq 10$ ms, Duty cycle $\leq 20\%$

2. Value on the alumina ceramic board (12.5 x 20 x 0.7 mm)

Electrical Characteristics

(Ta = 25°C)

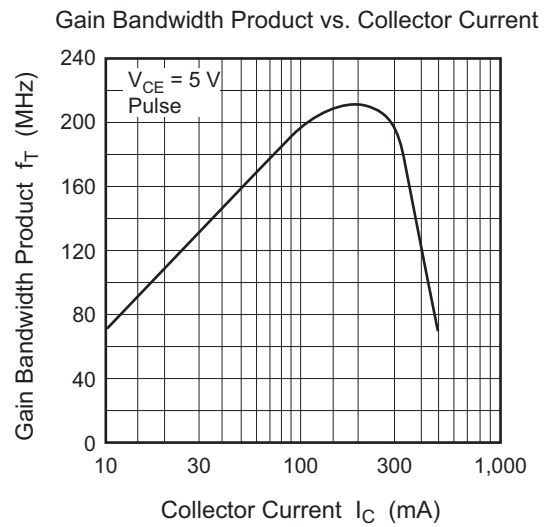
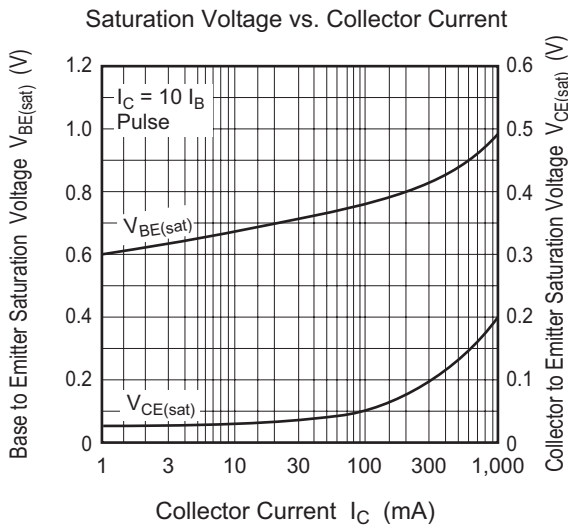
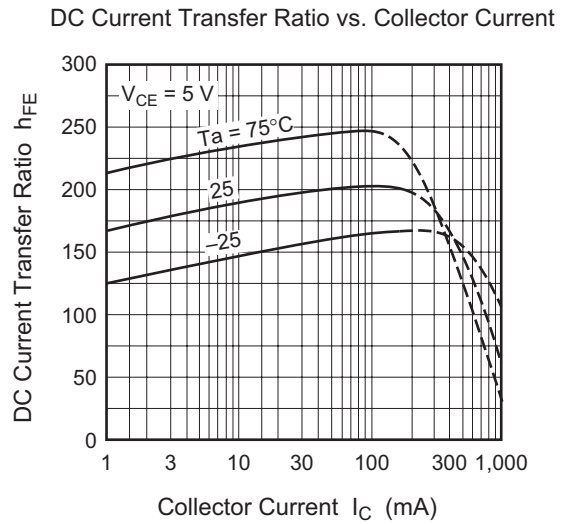
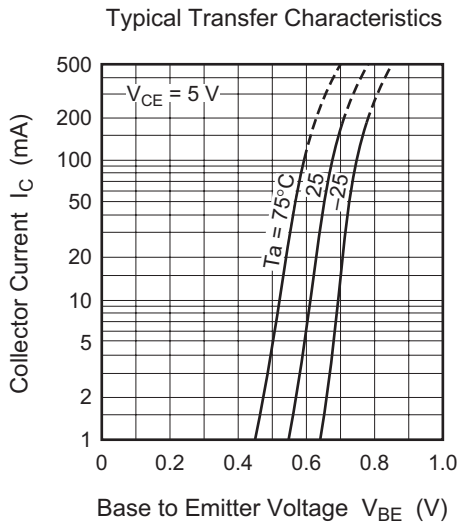
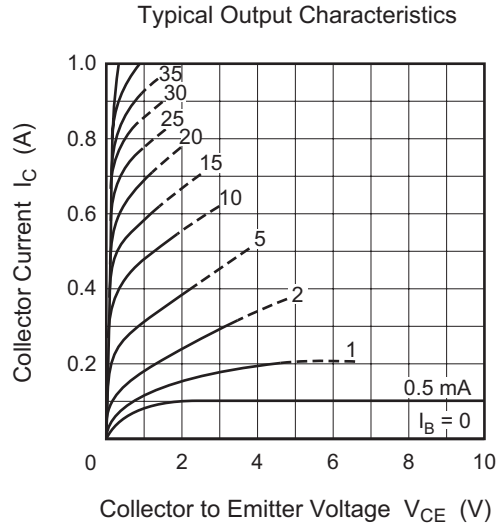
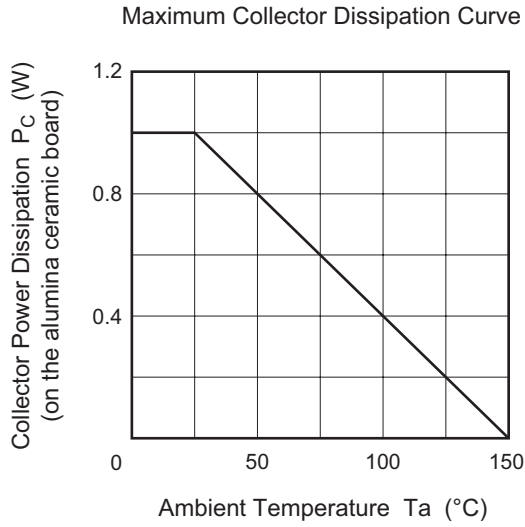
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	120	—	—	V	$I_C = 10 \mu A, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	80	—	—	V	$I_C = 1 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	—	—	V	$I_E = 10 \mu A, I_C = 0$
Collector cutoff current	I_{CBO}	—	—	10	μA	$V_{CB} = 100 \text{ V}, I_E = 0$
DC current transfer ratio	h_{FE1}^{*1}	60	—	320		$V_{EB} = 5 \text{ V}, I_C = 150 \text{ mA}^{*2}$
	h_{FE2}	30	—	—		$V_{CE} = 5 \text{ V}, I_C = 500 \text{ mA}^{*2}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	—	1	V	$I_C = 500 \text{ mA}, I_B = 50 \text{ mA}^{*2}$
Base to emitter voltage	V_{BE}	—	—	1.5	V	$V_{CE} = 5 \text{ V}, I_C = 150 \text{ mA}^{*2}$
Gain bandwidth product	f_T	—	140	—	MHz	$V_{CE} = 5 \text{ V}, I_C = 150 \text{ mA}^{*2}$
Collector output capacitance	C_{ob}	—	12	—	pF	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$

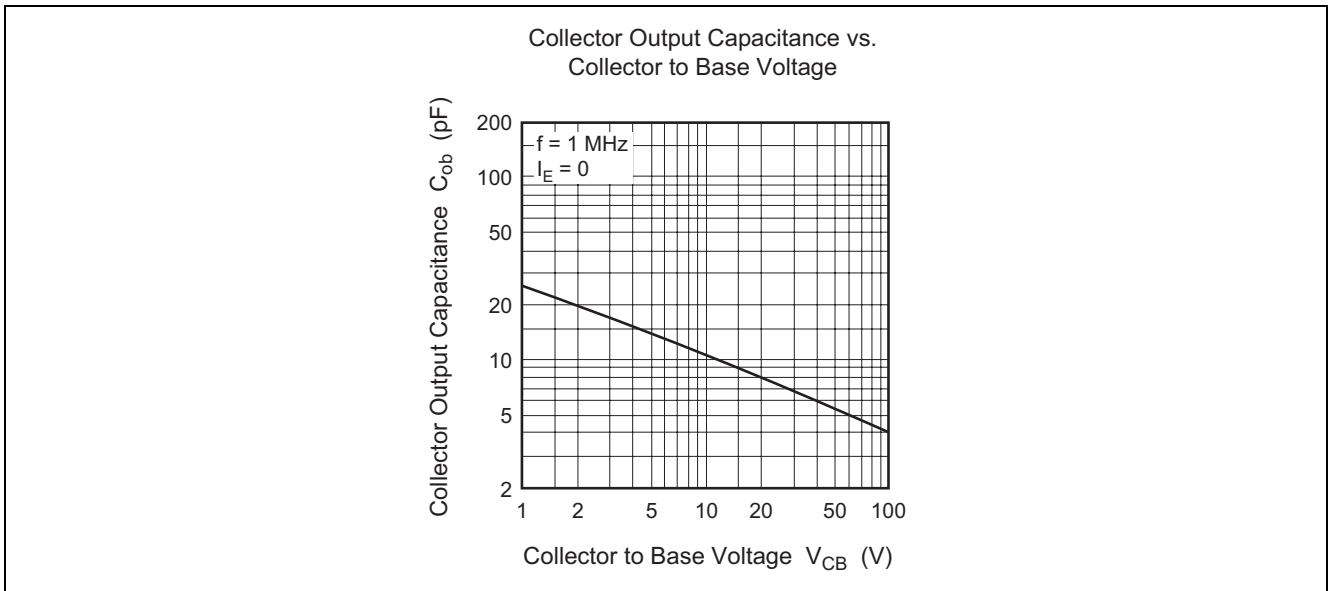
Notes: 1. The 2SD1418 is grouped by h_{FE1} as follows.

2. Pulse test

Mark	DA	DB	DC
h_{FE1}	60 to 120	100 to 200	160 to 320

Main Characteristics





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